

PY2N20

**Material Properties and
Phase Diagrams**

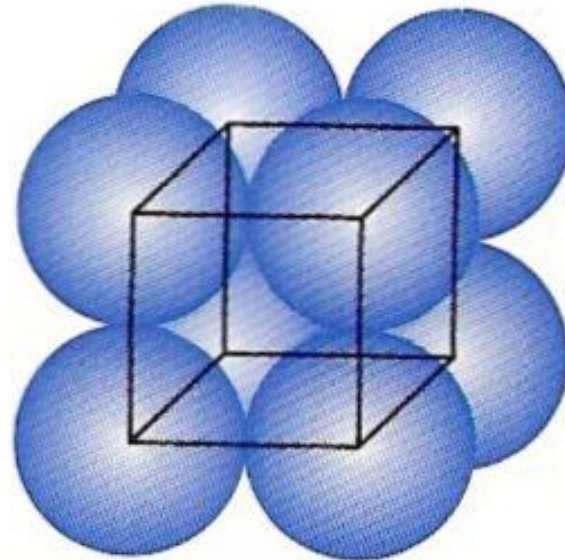
Lecture 2

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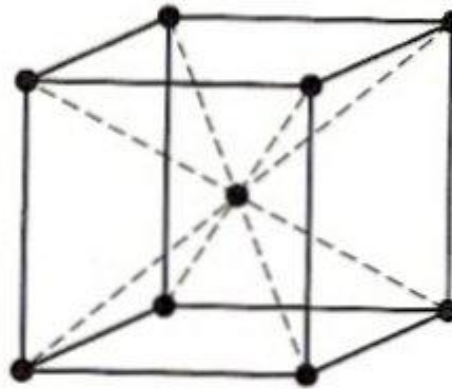
(Primitive) Cubic

- e.g. Mn
- Space group: I-43m (SG number: 217)
- Mn Structure: cubic
- Cell parameters:
 - a : 891.25 pm
 - b : 891.25 pm
 - c : 891.25 pm
 - α : 90.000°
 - β : 90.000°
 - γ : 90.000°

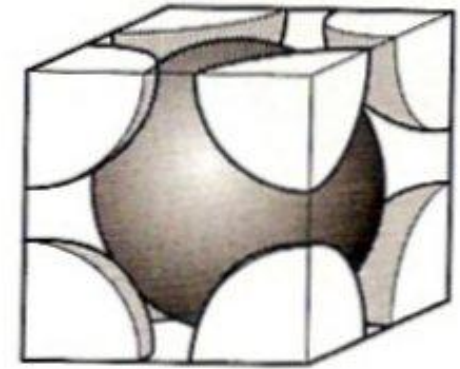


Body Centred Cubic (BCC)

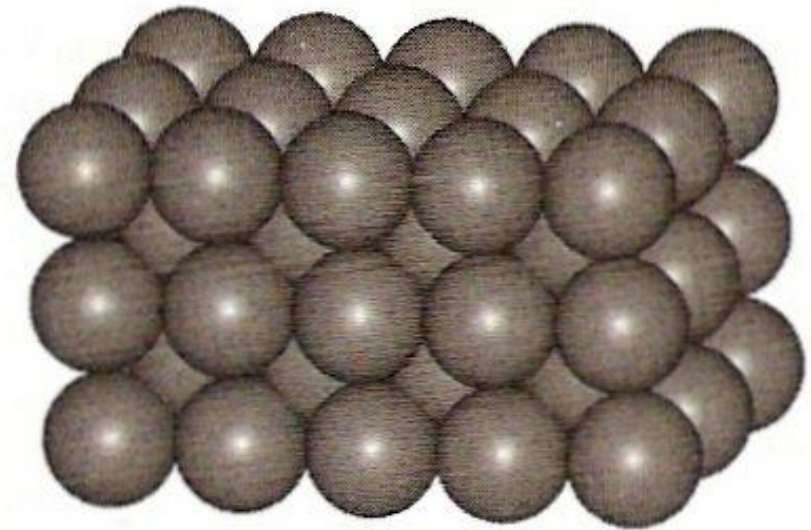
- e.g. α -Fe, V, Cr, Mo, W
- Space group: $Im\bar{3}m$ (SG number: 229)
- Fe Structure: bcc (body-centred cubic)
- Cell parameters:
 - a : 286.65 pm
 - b : 286.65 pm
 - c : 286.65 pm
 - α : 90.000°
 - β : 90.000°
 - γ : 90.000°



(a)



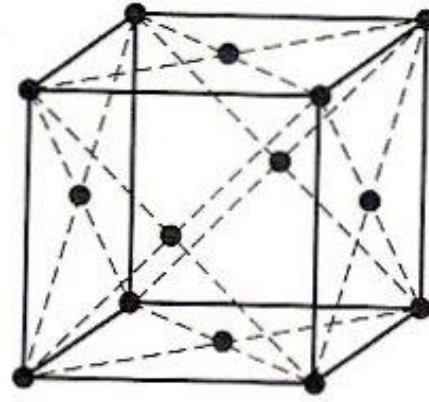
(b)



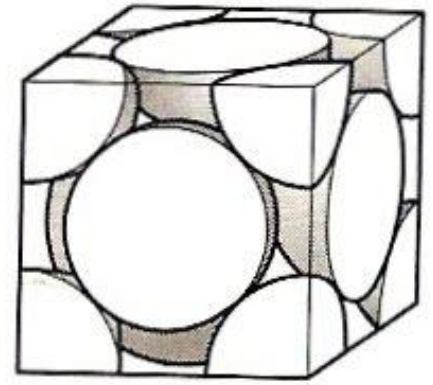
(c)

Face Centred Cubic (FCC)

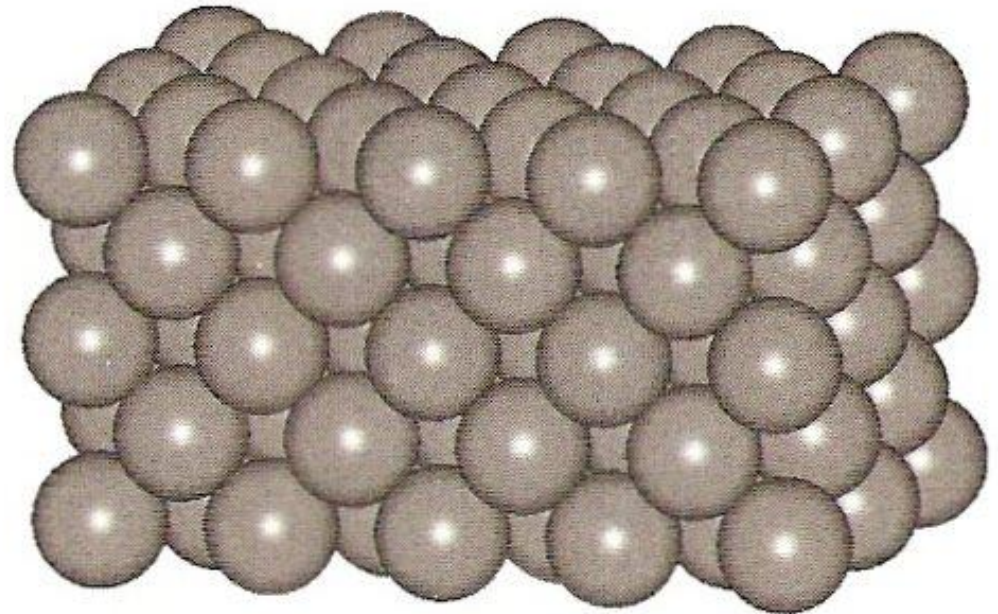
- e.g. γ -Fe, Al, Ni, Cu, Ag, Pt, Au
- Space group: Fm-3m
SG number: 225)
- Al Structure: ccp (cubic close-packed)
- Cell parameters:
 - a : 404.95 pm
 - b : 404.95 pm
 - c : 404.95 pm
 - α : 90.000°
 - β : 90.000°
 - γ : 90.000°



(a)



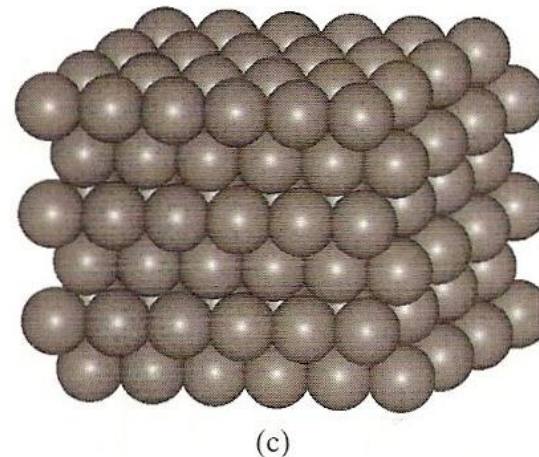
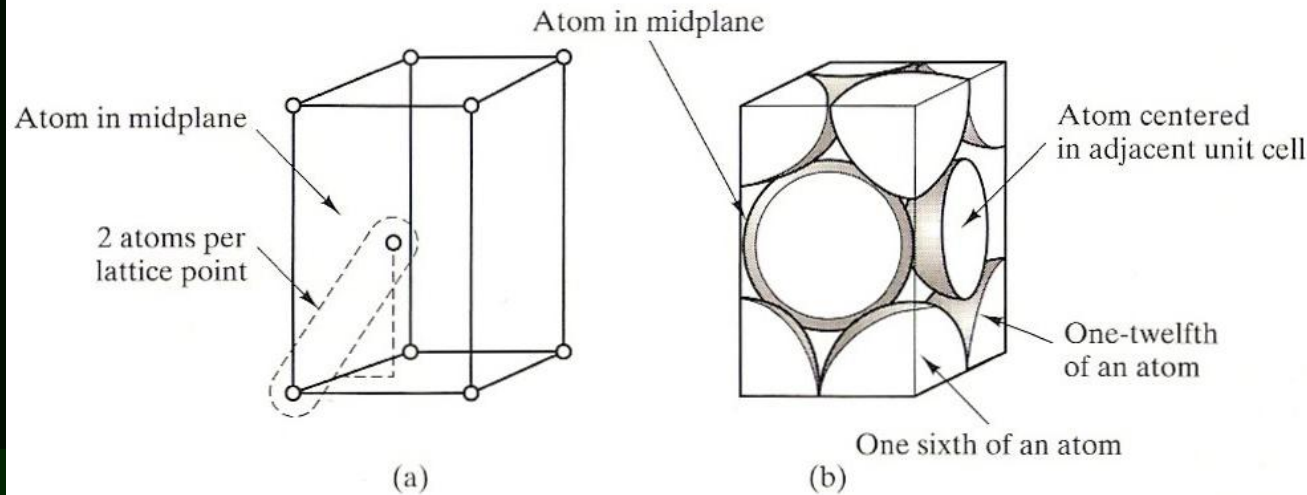
(b)



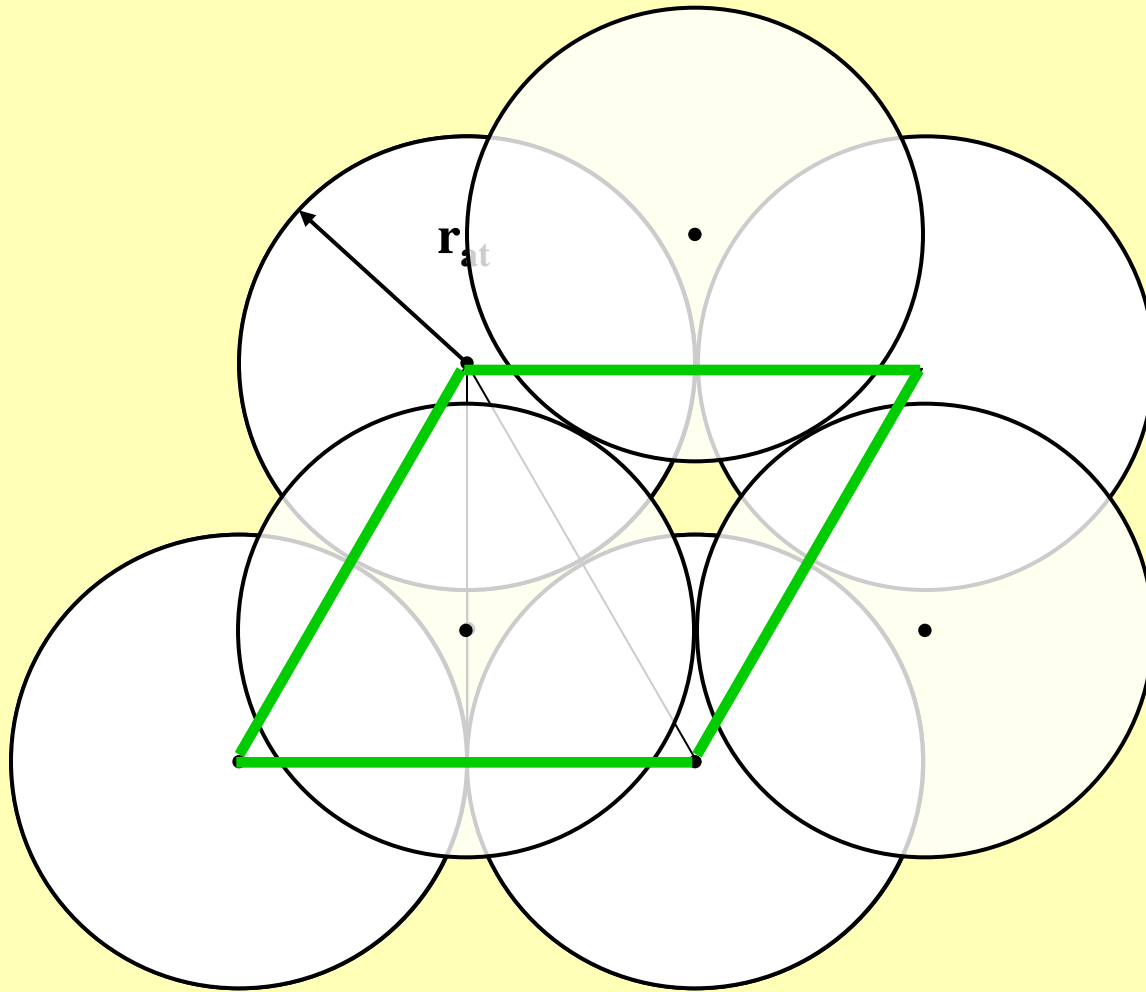
(c)

Hexagonal Close Packed (HCP)

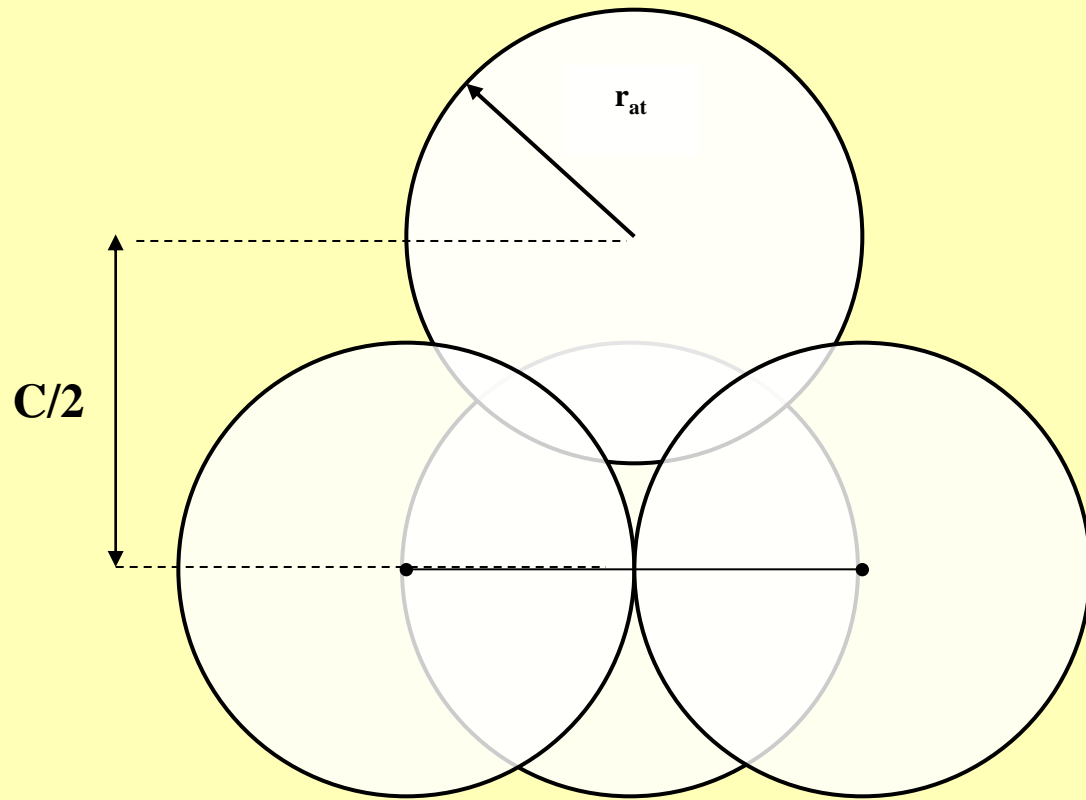
- e.g. Be, Mg, α -Ti, Zn, Zr
- Space group: P63/mmc
- (SG number: 194)
- Zn Structure: hcp
- Cell parameters:
 - a : 266.49 pm
 - b : 266.49 pm
 - c : 494.68 pm
 - α : 90.000°
 - β : 90.000°
 - γ : 120.000°



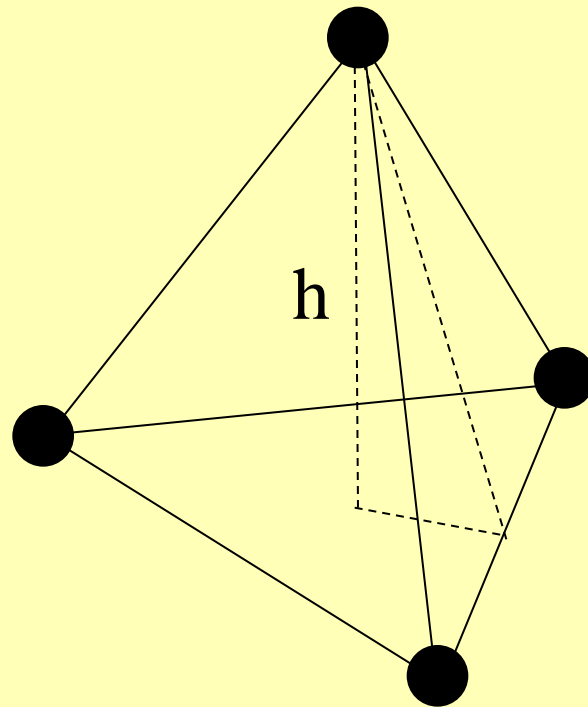
HCP Unit cell – plan view



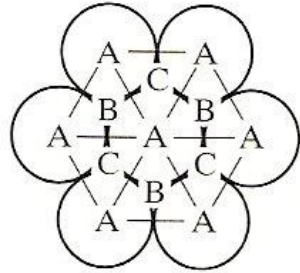
HCP Unit cell – side view



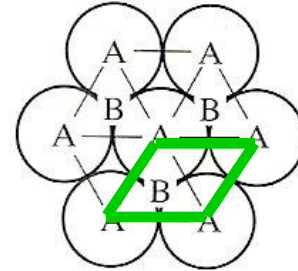
HCP reduced sphere view



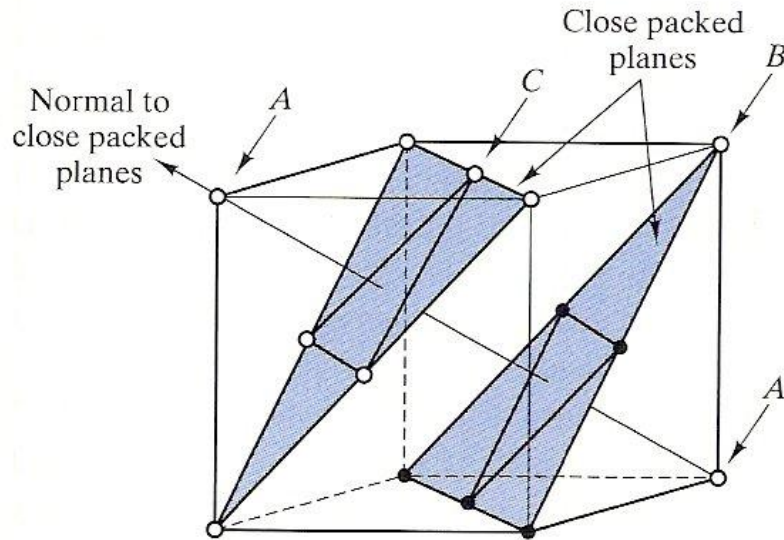
Close Packing FCC vs. HCP



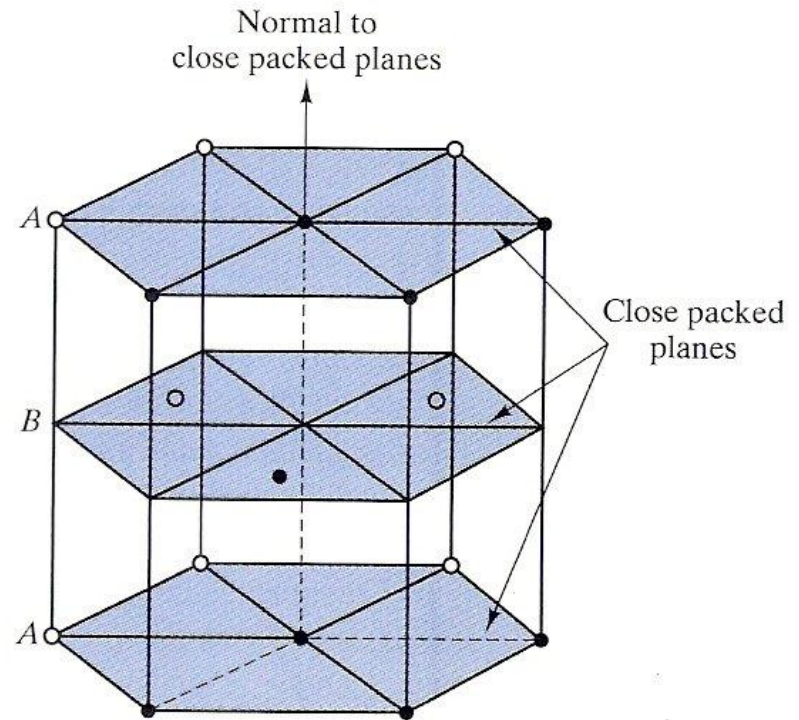
(a) Stacking of close packed planes



(b) Stacking of close packed planes



(c) Face-centered cubic

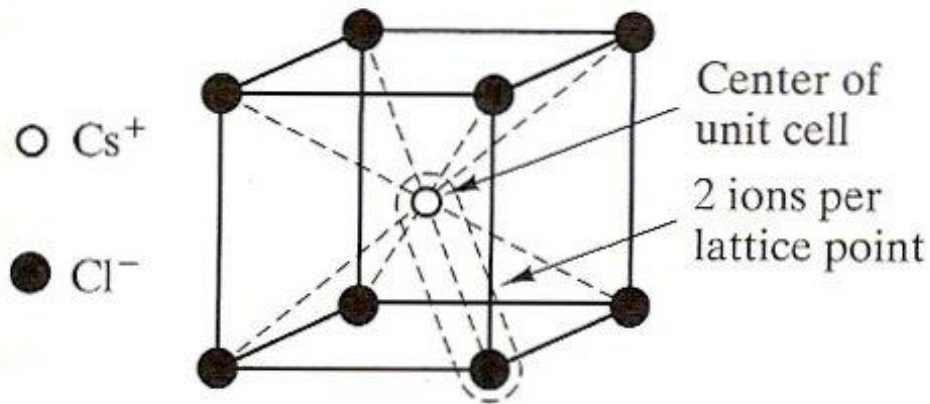


(d) Hexagonal close packed

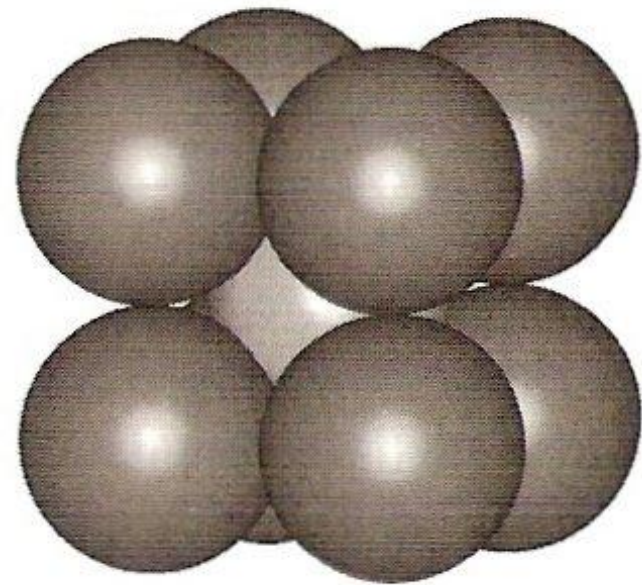
Caesium chloride

Cubic

- (Primitive) cubic



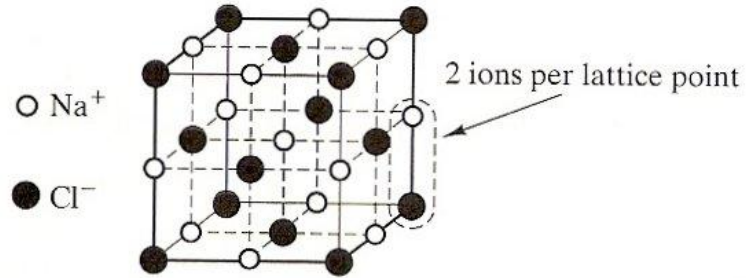
(a)



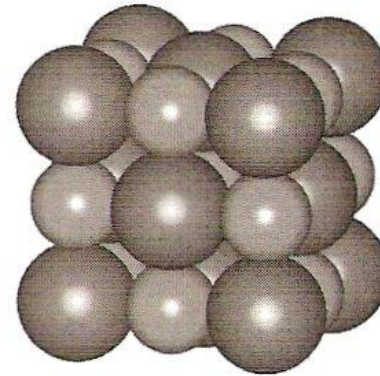
(b)

Sodium chloride

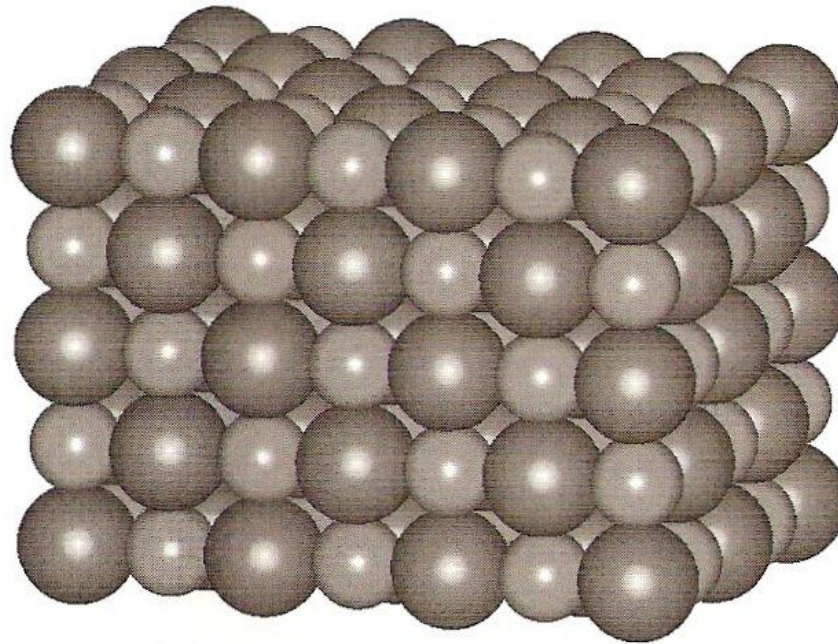
FCC



(a)



(b)



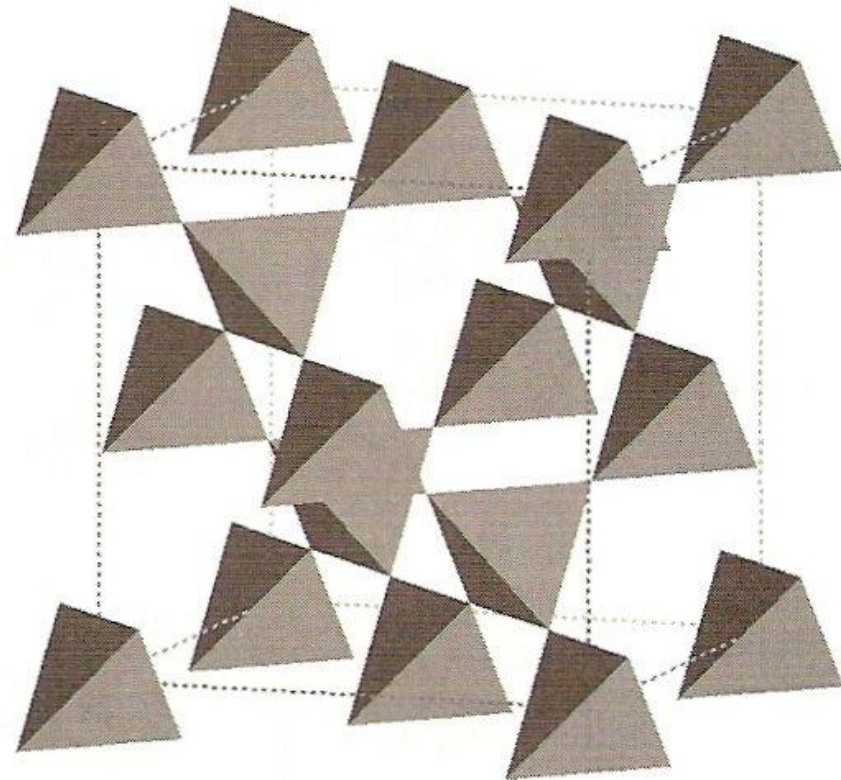
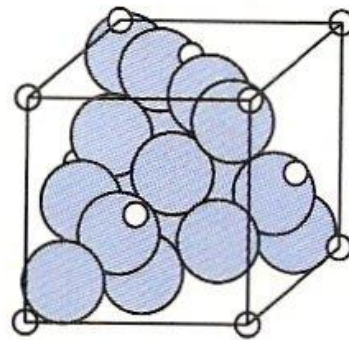
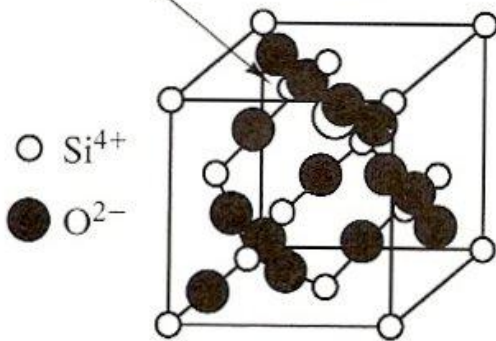
(c)

Cristobalite

FCC

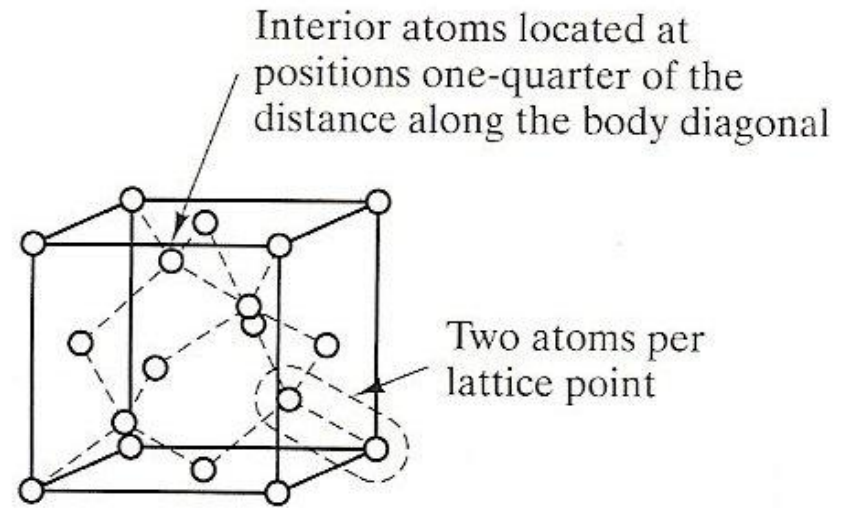
- e.g. SiO_2

Interior Si^{4+} located at positions one-quarter of the distance along the body diagonal

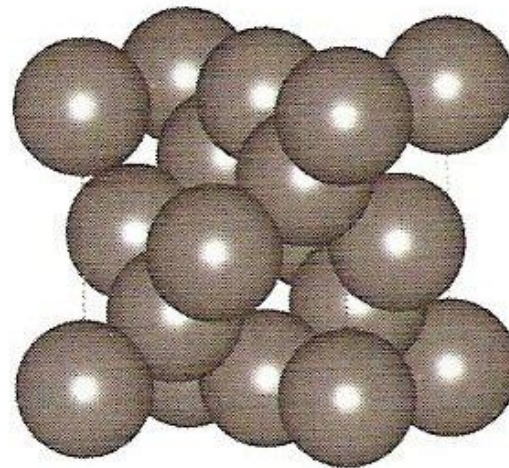


Diamond cubic (FCC)

- e.g. Si, Ge, grey-Sn



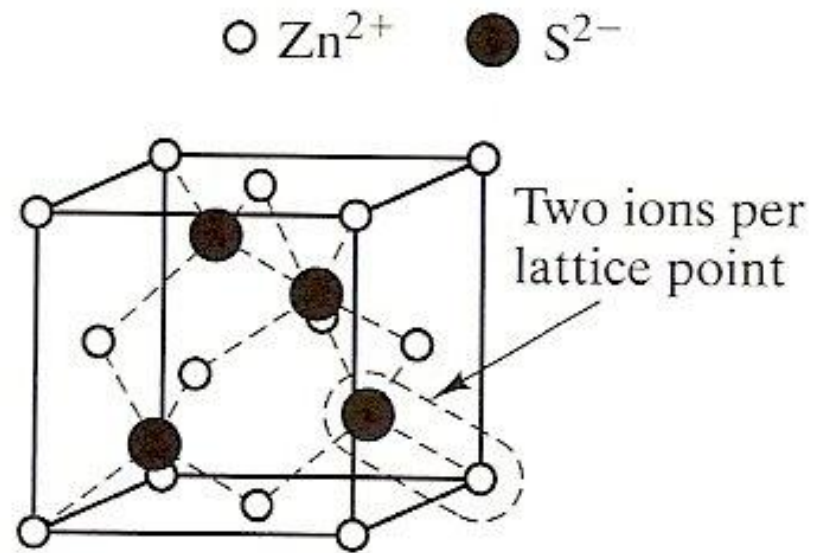
(a)



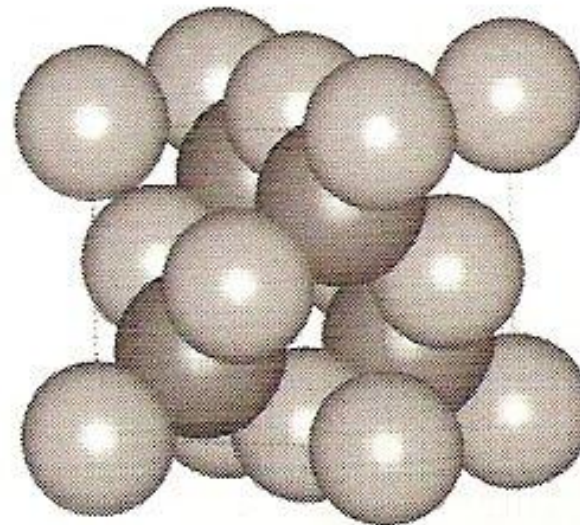
(b)

Zinc blende (FCC)

- e.g. GaAs,
AlP, InSb
(III-V SCs)
ZnS, CdS,
HgTe
(II-VI SCs)



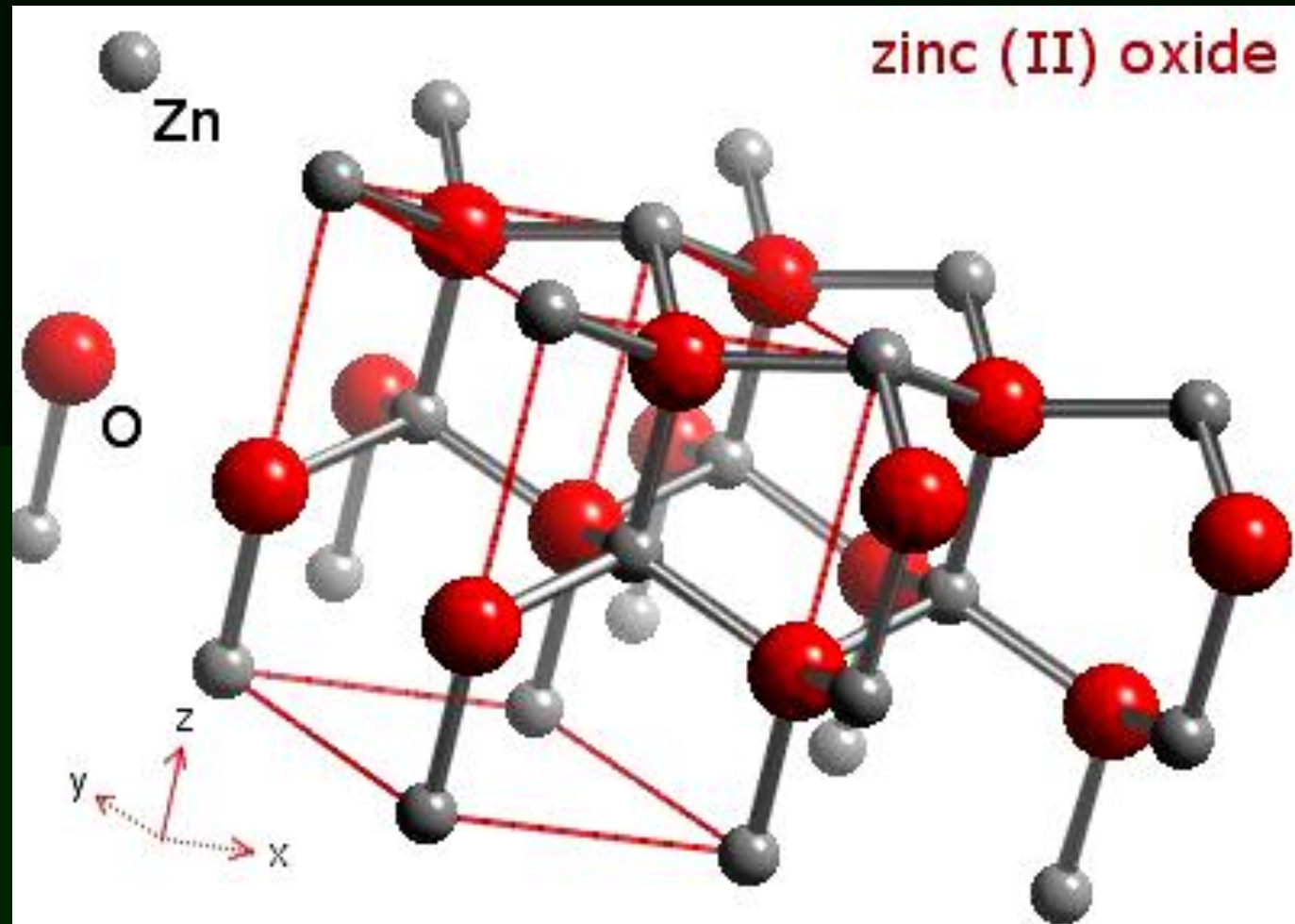
(a)



(b)

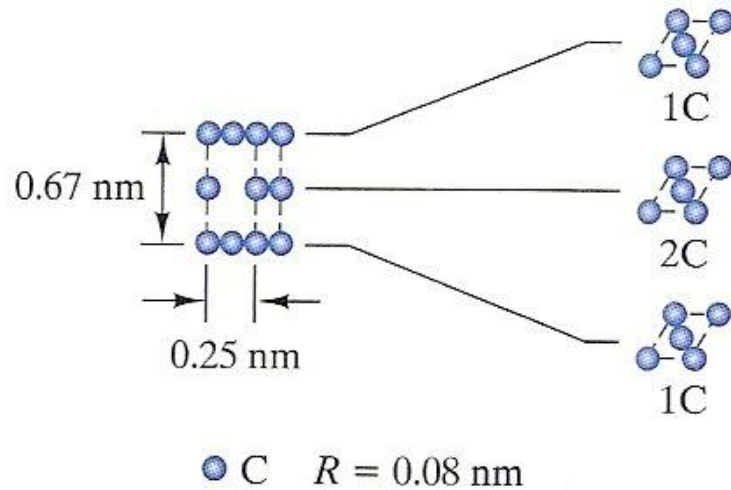
Wurtzite (Hexagonal)

- e.g. ZnS, ZnO, CdS

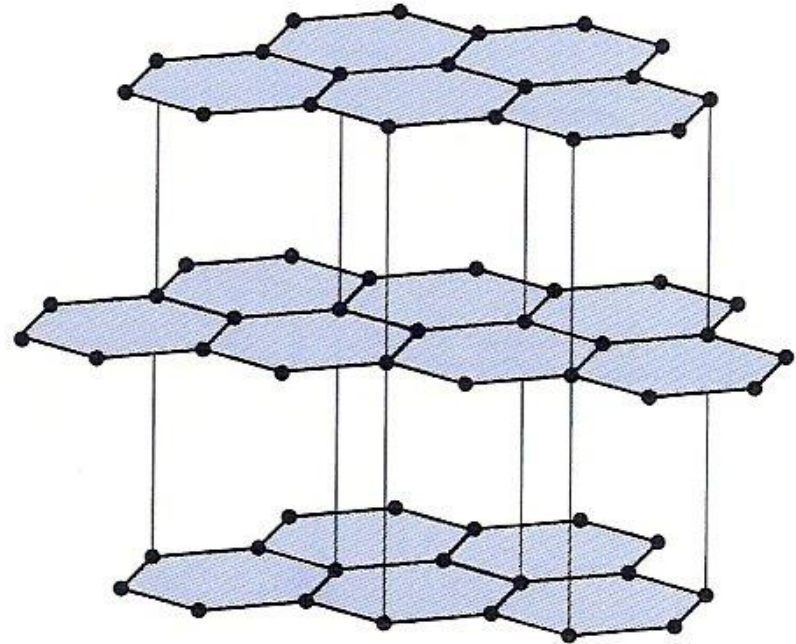


Carbon polymorphism

- Graphite



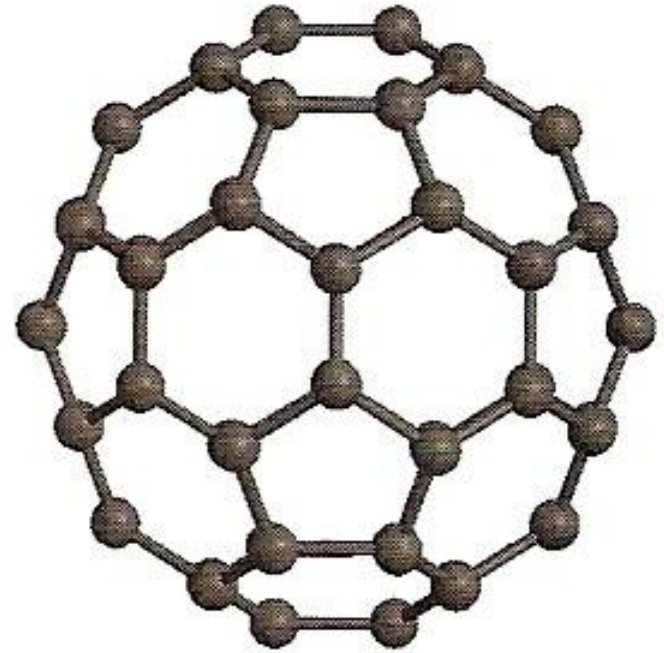
(a)



(b)

Carbon polymorphism

- Buckminster Fullerene C₆₀
- Carbon nanotube



(a)



(b)

Calculation of Density

- The density of a crystalline material can be calculated by

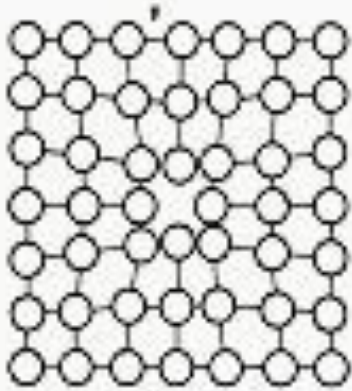
$$\rho = \frac{n \cdot \text{atomic mass}}{Vol_{Unit\ Cell}}$$

or

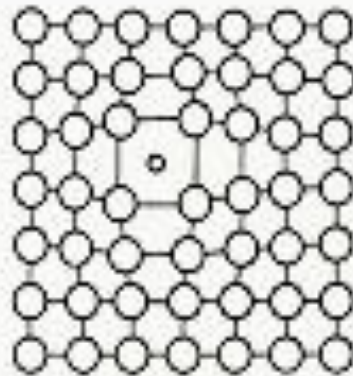
$$\rho = \frac{n \cdot \text{atomic weight}}{N_A \cdot Vol_{Unit\ Cell}}$$

Imperfections

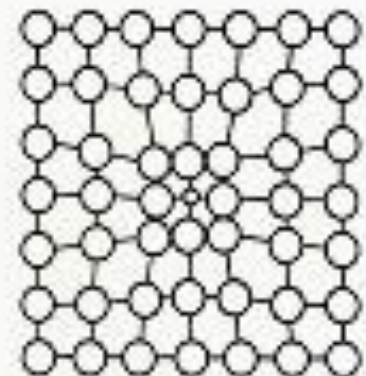
- Point defects



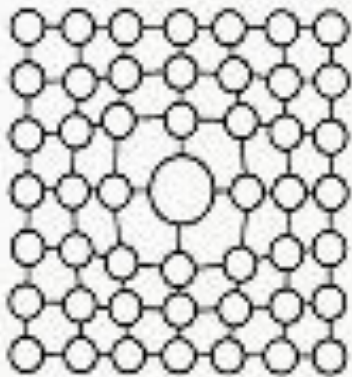
(a)



(b)



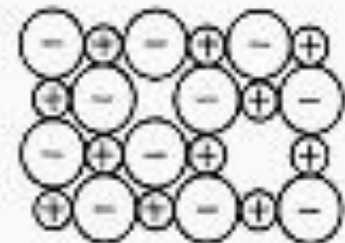
(c)



(d)

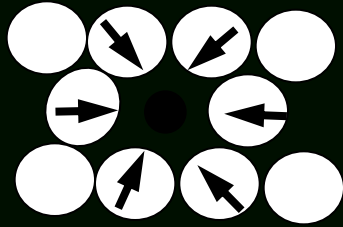


(e)

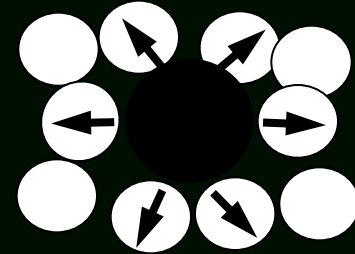


(f)

Lattice strains



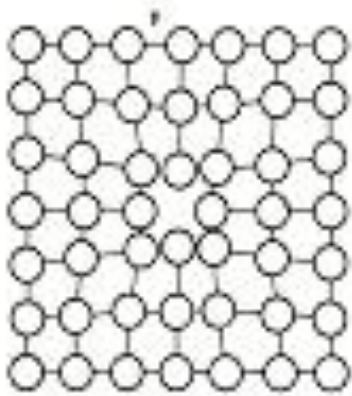
Tensile



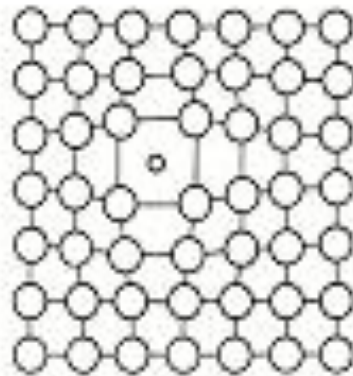
Compressive

Notice lattice strains

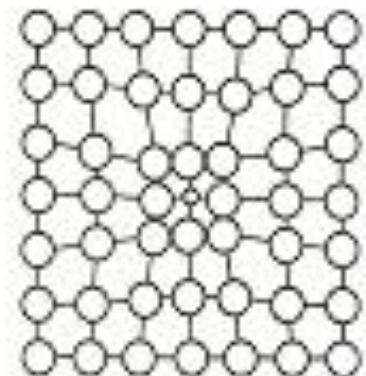
- Point defects



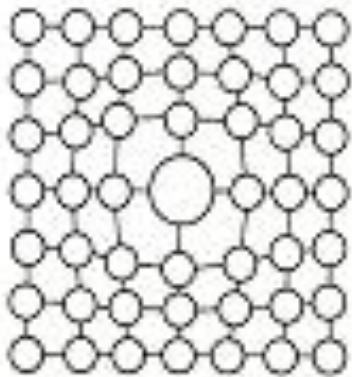
(a)



(b)



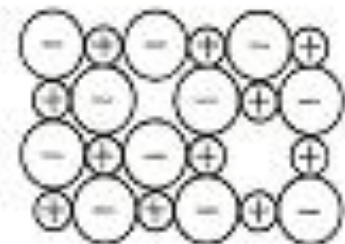
(c)



(d)



(e)



(f)

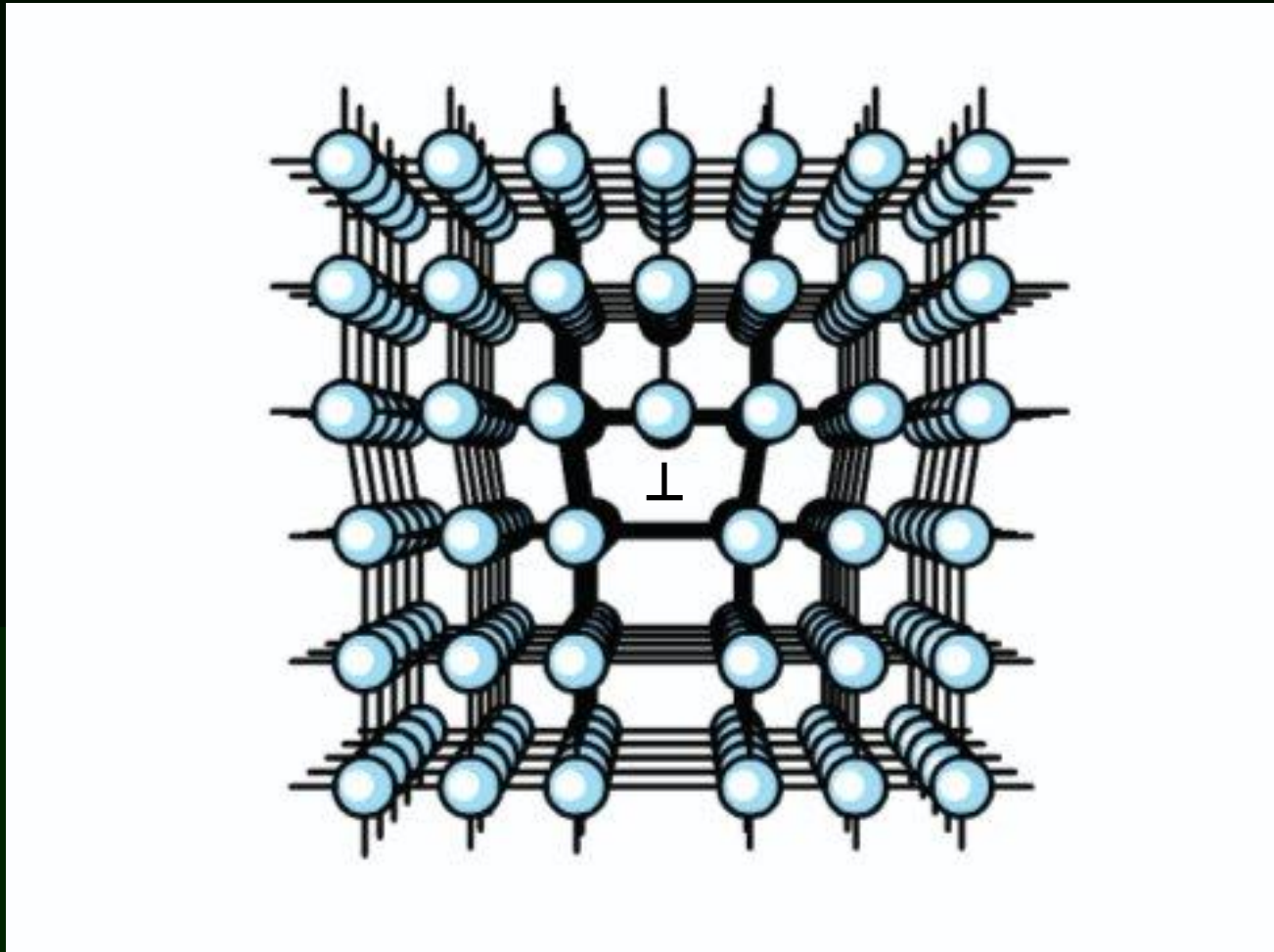
Number of Defects

- Number of vacancies (N_V) is given by

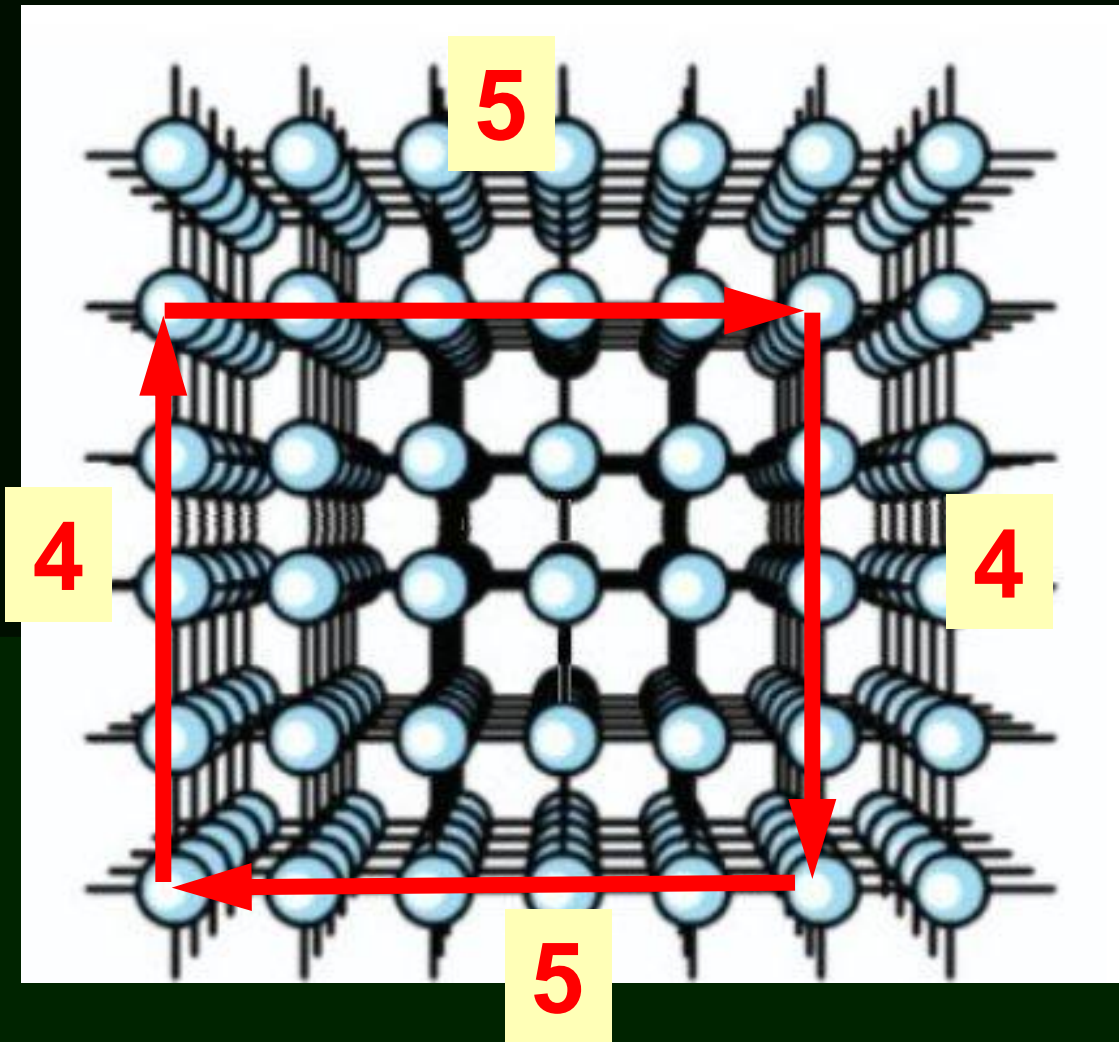
$$N_V = N_0 e^{-E_a / kT}$$

where N_0 is number of atomic sites and E_a is the activation energy for the formation of a vacancy.

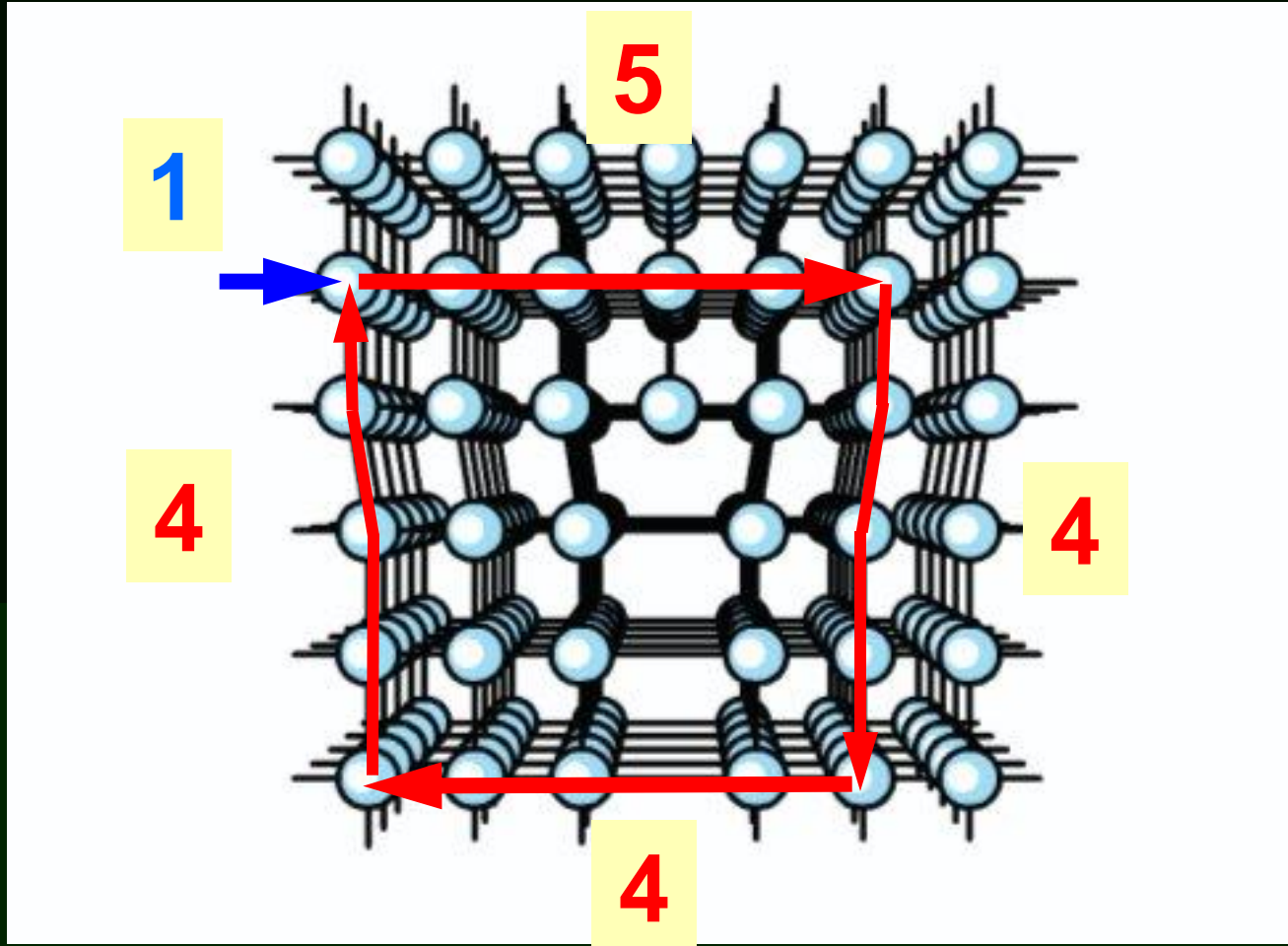
Edge Dislocation



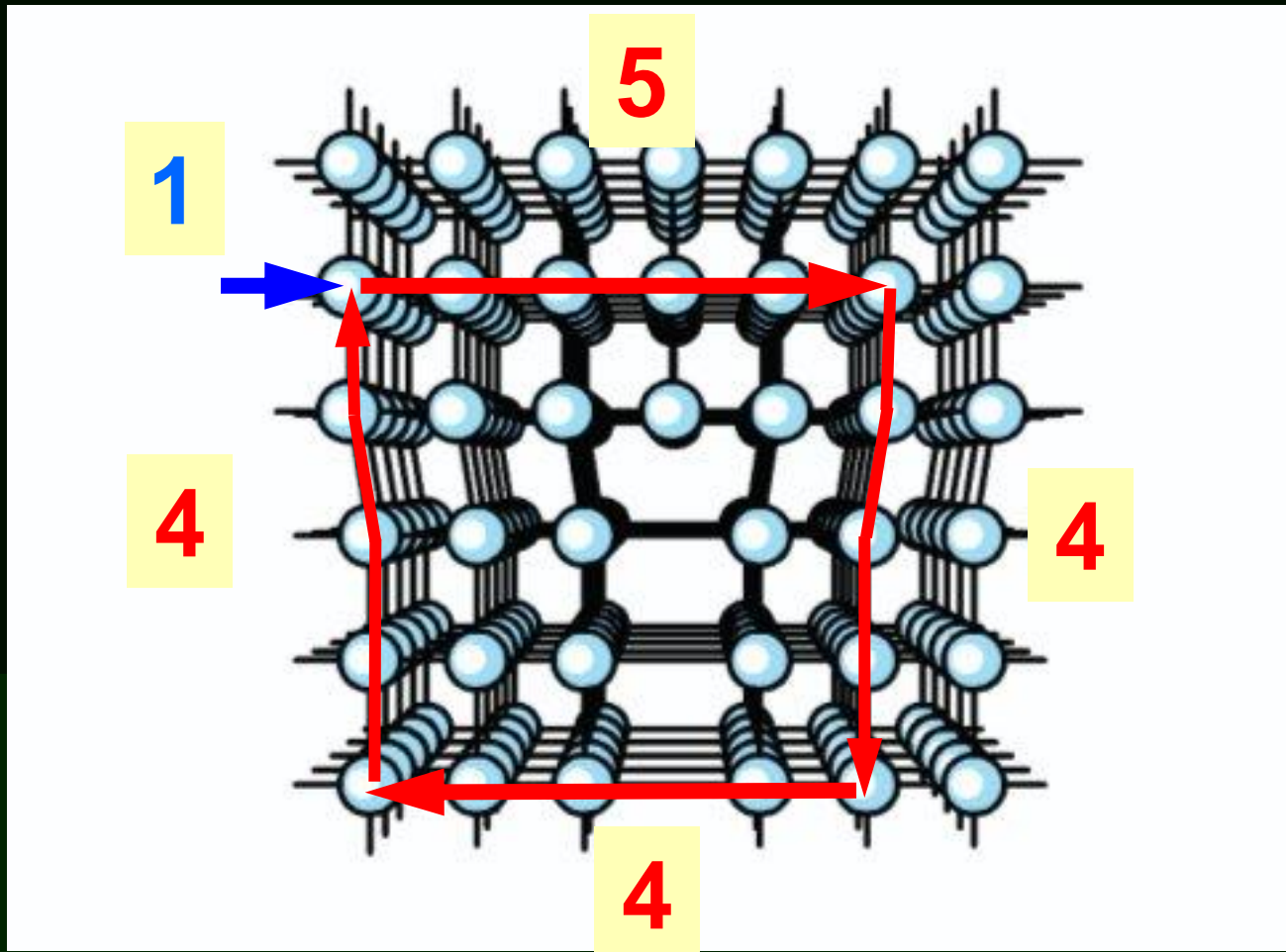
Perfect Crystal



Edge Dislocation

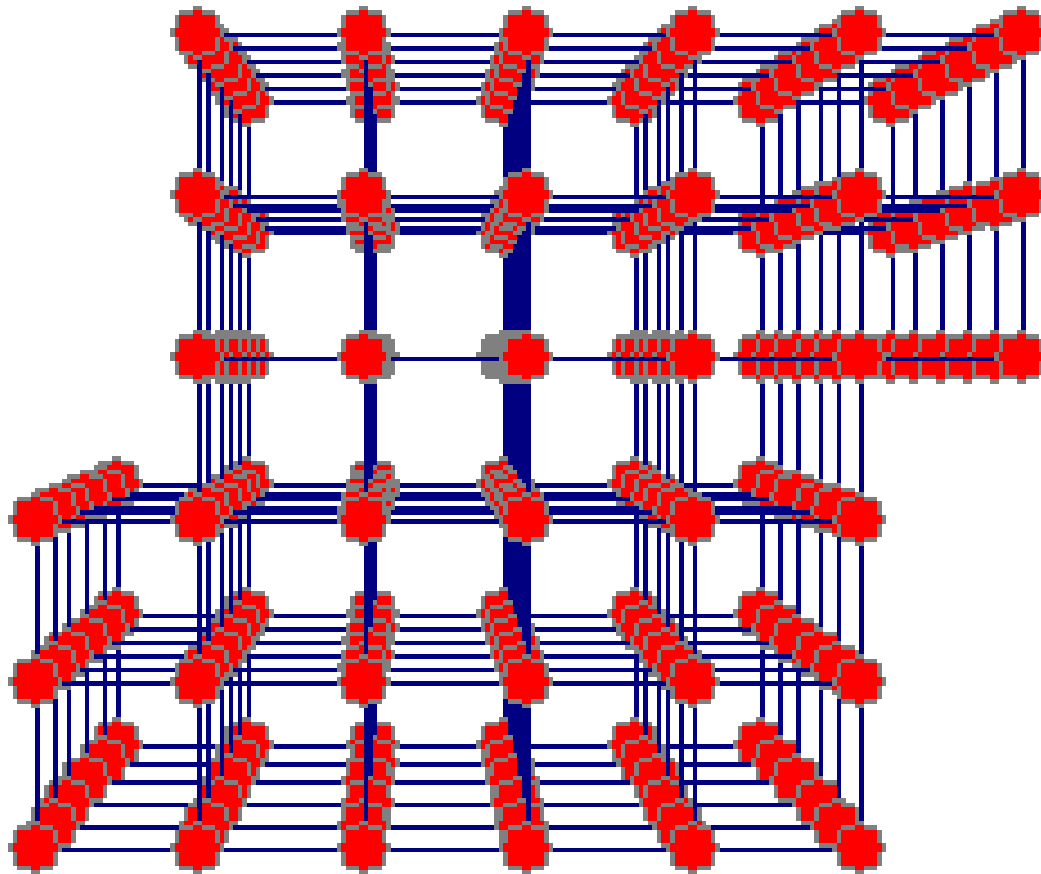


Burgers Vector

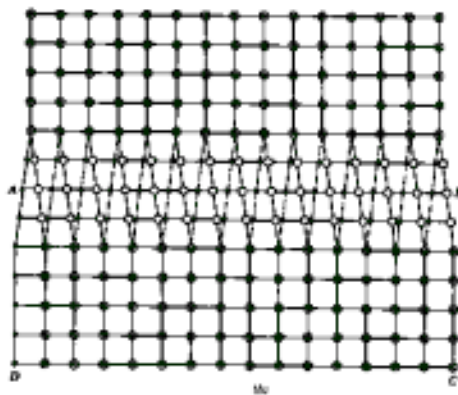
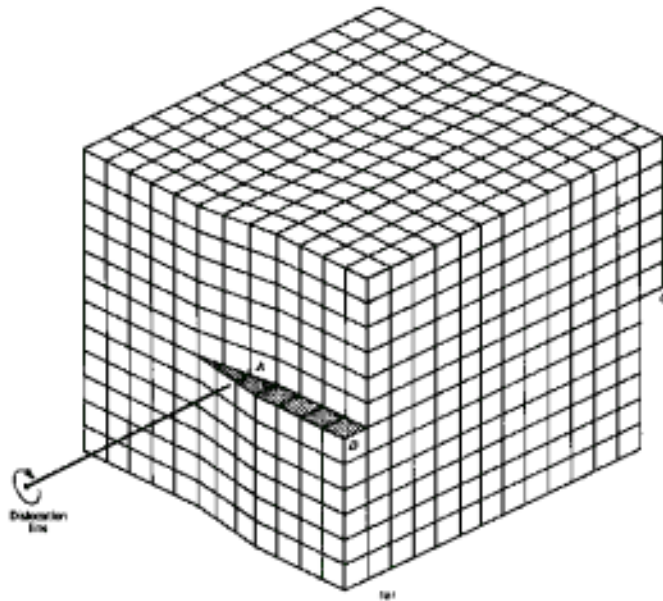


- The vector necessary to complete 'close' a path 'surrounding' the dislocation.

Edge Dislocation Motion



Screw Dislocation



Screw Dislocation

Screw Dislocation viewed from above

Dislocation along line AB

open circles: atoms above slip plane
closed circles: atoms below slip plane